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Interaction of the components in the Gd-Mn-Sn ternary system at 873 and 673 K

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The interaction of the components in the Gd-Mn-Sn ternary system was studied using the methods of X-ray and microstructure analyses, in the whole concentration range. The isothermal sections of the phase diagrams of the Gd-Mn-Sn system were constructed at 873 and 673 K. At both temperatures of investigation the Gd-Mn-Sn system is characterized by formation of two ternary compounds: GdMn₆Sn₆ (MgFe₆Ge₆ structure type, space group *P6/mmm*) and Gd₄Mn₄Sn₇ (Zr₄Co₄Ge₇ structure type, space group *I4/mmm*). The formation of the interstitial solid solution GdMn_xSn₂ based on GdSn₂ (ZrSi₂-type) binary compound was observed up to 10 at. % Mn at 873 K and 673 K. The existence of the substitutional solid solution based on GdMn₂ (MgCu₂-type) was observed up to 5 at.% Sn and 3 at. % Sn at 873 K and 673 K, respectively.

Keywords: inetmetallics, ternary system, phase equilibria, crystal structure, solid solution.

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Introduction

Intermetallics of rare earth metals (R) cause the special attention of the scientists as a basis for searching and creation of new perspective magnetic materials. Partially, widely studied the magnetic properties of compounds contained magnetic rare earths and magnetic *d*-elements (iron, cobalt, nickel). The basic step for searching of new materials is investigation of component interaction in metallic systems which give the possibility to determine the temperature and concentration range of existence of intermediate phases, influence of some factors on their stability, as important characteristics for next study of physical properties. During investigation of the ternary stannides with rare earths and manganese (R = Y, Pr, Nd, Sm, Gd-Lu) the existence of the ternary compounds with stoichiometry 1:6:6 was found and it was established that they crystallize with MgFe₆Ge₆, HoFe₆Sn₆, and SmMn₆Sn₆ structure types [1-7]. Among RMn₆Sn₆ stannides the SmMn₆Sn₆ compound is characterized by three structural modifications with MgFe₆Ge₆, YCo₆Ge₆ and SmMn₆Sn₆ (disordered variant of HfFe₆Ge₆-type) structure types depending on temperature of annealing. Magnetic property measurements of RMn₆Sn₆ compounds indicated considerable influence of manganese atoms on magnetic behavior of these compounds which order ferro- or

ferrimagnetically with temperature of magnetic ordering higher that room temperature (including the compounds with nonmagnetic rare earth metals Y, Lu) [3-6, 8]. In the most R-Mn-Sn systems also the ternary compounds with Zr₄Co₄Ge₇ structure type were found [9]. It worth to note that except the compounds with Zr₄Co₄Ge₇ and MgFe₆Ge₆ structure types for stannides with manganese, Tm and Lu the formation of compounds with Hf₃Cr₂Si₄-type was found [10], and Mg₅Si₆-type is realized only for Yb₄Mn₂Sn₅ stannide [11].

Taking into account the low melting temperature of tin (505.05 K), the most of the studied R-M-Sn ternary systems (M – *d*-element) were investigated at 670 K [12]. The higher temperature of annealing used during investigation of some R-{Cu,Ag}-Sn and R-Ni-Sn systems indicated an influence of temperature factor on stability of ternary compounds with high Sn content [13, 15]. With the aim to study an influence of annealing temperature on interaction of the components, formation of solid solutions and stability of intermediate phases we studied the Gd-Mn-Sn system at 873 and 673 K. Experimental results of this investigation are given in the presented work.

I. Experimental

To study the phase equilibria in the Gd-Mn-Sn system 31 ternary and 13 binary samples were prepared by arc melting of the constituent elements (content of the basic component not lower than 99.9 wt. %). The homogenizing annealing of separate particles of the synthesized alloys was performed in the evacuated up to 0.1 Pa quartz tubes for 720 hours at temperatures 873 K and 673 K with subsequently quenching in ice water. X-ray phase analysis of the samples was carried out using the powder patterns obtained on DRON-2.0 (FeK α radiation) diffractometer. The observed diffraction intensities were compared with reference powder patterns of binary, known ternary phases and pure elements. The chemical and phase compositions of the obtained samples were examined by Scanning Electron Microscopy (SEM) using REMMA-102-02 scanning electron microscope. The data for the crystal structure refinements were collected at room temperature using STOE STADI P diffractometer (graphite monochromator, CuK α radiation, 20 - 100° 2 θ range with scanning step 0.02°). Calculations of the crystallographic parameters and theoretical patterns were performed using the WinPLOTR [16] program packages.

II. Results and discussion

For construction of the phase diagrams of Gd-Mn-Sn ternary system at 873 K and 673 K we prepared and analyzed 31 ternary and 13 binary alloys. After annealing all synthesized samples were examined by X-ray phase and microstructure analyses. The isothermal sections of the Gd-Mn-Sn system at 873 K and 673 K are presented

in Figs. 1, 2, respectively. In the Mn-Sn and Gd-Mn binary systems the presence of the all binary compounds corresponding to the reference data [17-20] was confirmed at both temperature of investigation. At 873 K only two compounds – Mn₃Sn, Mn₂Sn, were formed in Mn-Sn system that corresponds to the reported phase diagram according to which MnSn₂ binary exists up to ~820 K. According to EDX data the homogeneity range of Mn₂Sn compound is limited by Mn_{67.81}Sn_{32.11} and Mn_{63.87}Sn_{36.73} compositions. GdMn₂ binary at stoichiometric composition crystallizes in MgCu₂ structure type. To check the formation of GdMn₂ binary with MgZn₂-type [21] in course of our investigation two alloys with Gd₃₇Mn₆₃ and Gd₄₀Mn₆₀ compositions were prepared and annealed at 673 and 873 K. Performed phase analysis of the Gd₃₇Mn₆₃ and Gd₄₀Mn₆₀ samples indicated the presence of the main cubic phase GdMn₂ with MgCu₂-type and Gd. In the Gd-Sn binary system at both temperatures of annealing the existence of binaries Gd₅Sn₃ (Mn₅Si₃-type), Gd₅Sn₄ (Sm₅Ge₄-type), Gd₁₁Sn₁₀ (Ho₁₁Ge₁₀-type), GdSn₂ (ZrSi₂-type), Gd₃Sn₇ (Gd₃Sn₇-type) and GdSn₃ was confirmed. GdSn₃ binary is characterized by polymorphic transformation at ~665 K, thus at 873 K belongs to Cu₃Au structure type [19], and at 673 K is characterized by orthorhombic structure of GdSn_{2.75}-type [20].

A formation of interstitial solid solutions based on the RSn₂ (R- rare earths of Yttrium group) series of binary compounds with ZrSi₂ structure was studied and reported in Ref. [22]. During investigation of Gd-Mn-Sn system the existence of interstitial solid solution GdMn_xSn₂ based on the GdSn₂ binary (ZrSi₂-type) was observed. The solubility of Mn atoms was found to be up to 10 at. % (GdMn_{0.33}Sn₂) at both temperatures 873 K and 673 K. The lattice parameters change from $a = 0.4431(2)$, $b = 1.6408(8)$, $c = 0.4325(4)$ nm (for

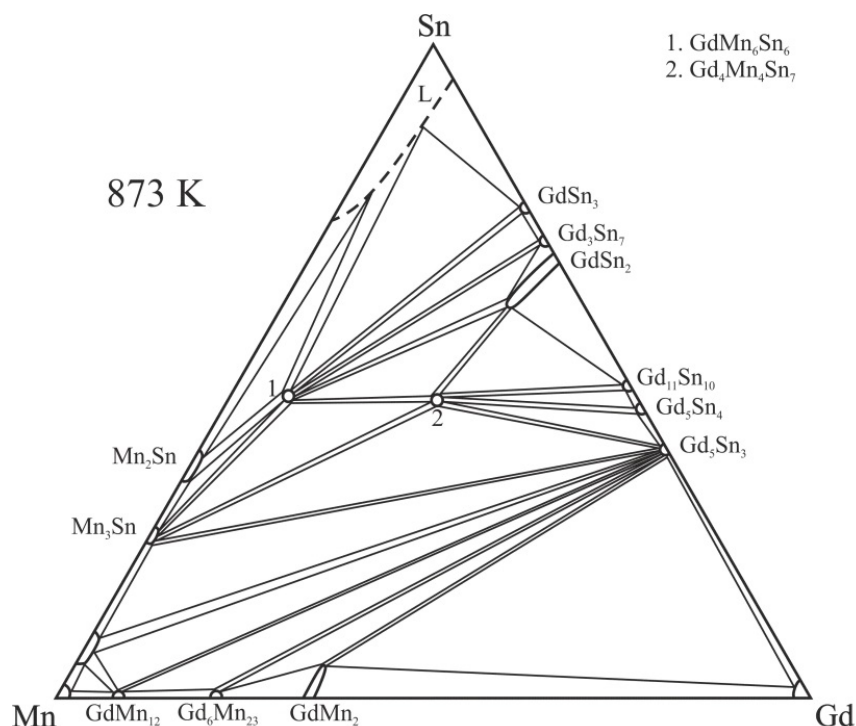


Fig. 1. Isothermal section of Gd-Mn-Sn system at 873 K.

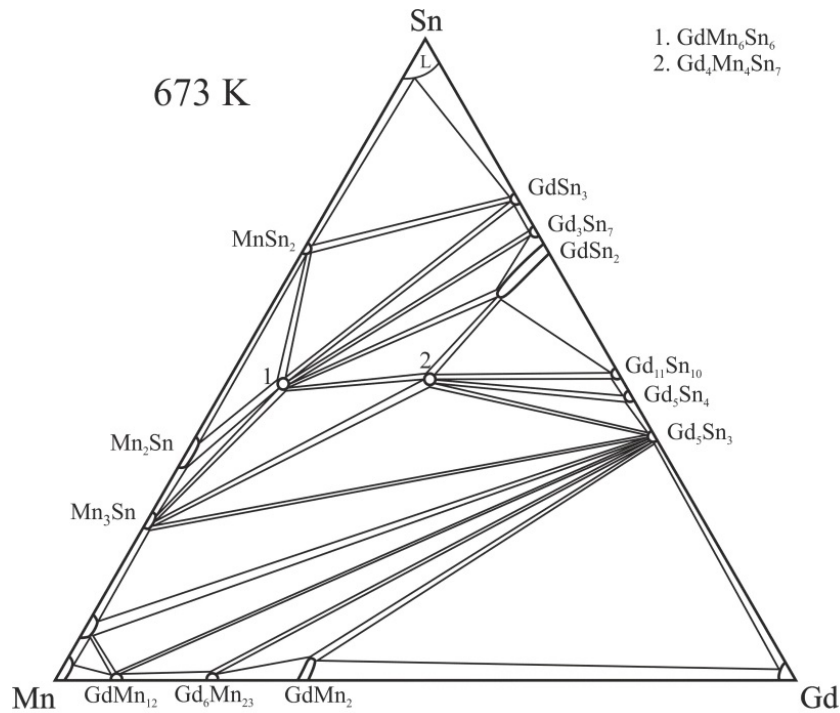


Fig. 2. Isothermal section of Gd-Mn-Sn system at 673 K.

Table 1

Crystallographic characteristics of the ternary compounds in Gd-Mn-Sn system

Compound	Structure type	Space group	Lattice parameters, nm		
			<i>a</i>	<i>b</i>	<i>c</i>
GdMn ₆ Sn ₆	MgFe ₆ Ge ₆	<i>P6/mmm</i>	0.55304(9)	–	0.9014(2)
Gd ₄ Mn ₄ Sn ₇	Zr ₄ Co ₄ Ge ₇	<i>I4/mmm</i>	1.5246(8)	–	0.5892(5)

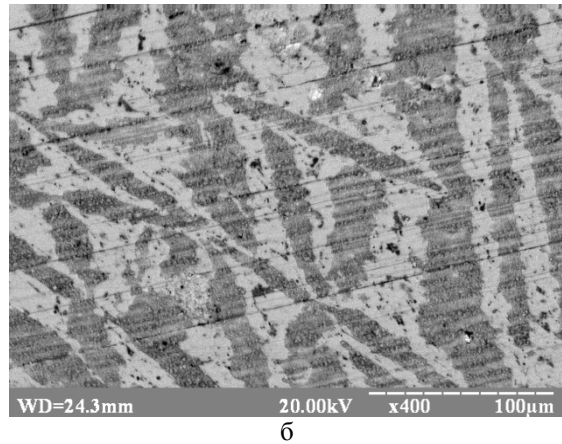
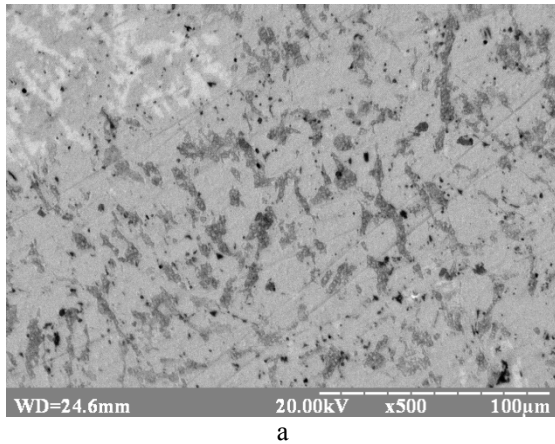


Fig. 3. Electron micrographs and phase compositions of the alloys at 873 K: *a*) Gd₂₈Mn₂₆Sn₄₆ (light phase – GdMn_xSn₂, grey phase – Gd₄Mn₄Sn₇, dark phase – GdMn₆Sn₆), *b*) Gd₂₉Mn₁₉Sn₅₂ (light phase – GdMn_xSn₂ (Gd_{30.45}Mn_{9.40}Sn_{60.15}), grey phase – Gd₄Mn₄Sn₇).

GdSn₂ compound) to $a = 0.4446(7)$, $b = 1.6461(8)$, $c = 0.4368(5)$ nm (for Gd₃₀Mn₁₀Sn₆₀ sample). Limited composition of the solid solution was confirmed by results of EDX analysis (Gd_{30.45}Mn_{9.40}Sn_{60.15}, Fig. 3,b). Phase analysis of samples in the ternary part of Gd-Mn-Sn system close to the Gd-Mn in Gd-Sn system indicated the formation of the substitutional solid solution based on GdMn₂ binary compound (MgCu₂ structure type) up to 3 at. % Sn at 673 K and up to 5 at. % Sn at 873 K

($a = 0.77515(6) - 0.77638(7)$ nm). Significant solubility of the third component in other binary compounds of Mn-Sn, Gd-Mn in Gd-Sn system was not observed under used conditions.

According to phase and microstructure analyses in the Gd-Mn-Sn system at both temperatures 873 K and 673 K the presence of two ternary compounds GdMn₆Sn₆ and Gd₄Mn₄Sn₇ was confirmed. Both GdMn₆Sn₆ and Gd₄Mn₄Sn₇ stannides are characterized by narrow

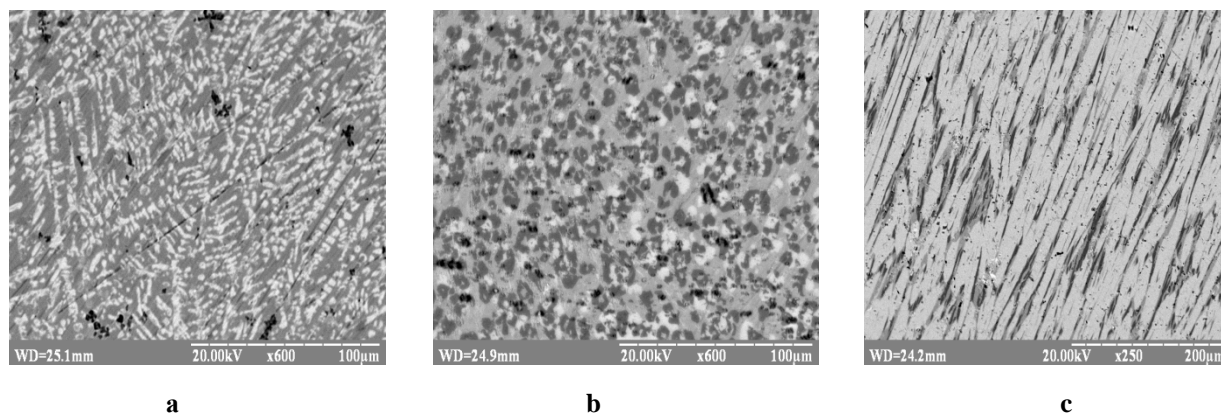


Fig. 4. Electron micrographs and phase compositions of the alloys at 673 K: *a*) $\text{Gd}_{42}\text{Mn}_{46}\text{Sn}_{12}$ (light phase – Gd_3Sn_3 , grey phase – $\text{GdMn}_{2-3}\text{Sn}_x$ (up to 3 at. % Sn)), *b*) $\text{Gd}_{10}\text{Mn}_{52}\text{Sn}_{38}$ (light phase – $\text{Gd}_4\text{Mn}_4\text{Sn}_7$, grey phase – GdMn_6Sn_6 , dark phase – Mn_3Sn), *c*) $\text{Gd}_{19}\text{Mn}_{39}\text{Sn}_{42}$ (light phase – $\text{Gd}_4\text{Mn}_4\text{Sn}_7$, grey phase – GdMn_6Sn_6 , dark phase – Mn_3Sn).

Table 2

Atomic coordinates and isotropic displacement parameters for GdMn_6Sn_6 compound

Atom	Wyckoff position	x/a	y/b	z/c	$B_{\text{iso}} \cdot 10^2$ (nm ²)
Gd	1a	0	0	0	1.55(1)
Mn	6i	1/2	0	0.2481(5)	0.34(10)
Sn1	2e	0	0	0.3370(4)	0.78(8)
Sn2	2c	1/3	2/3	0	0.40(9)
Sn3	2d	1/3	2/3	1/2	0.40(10)

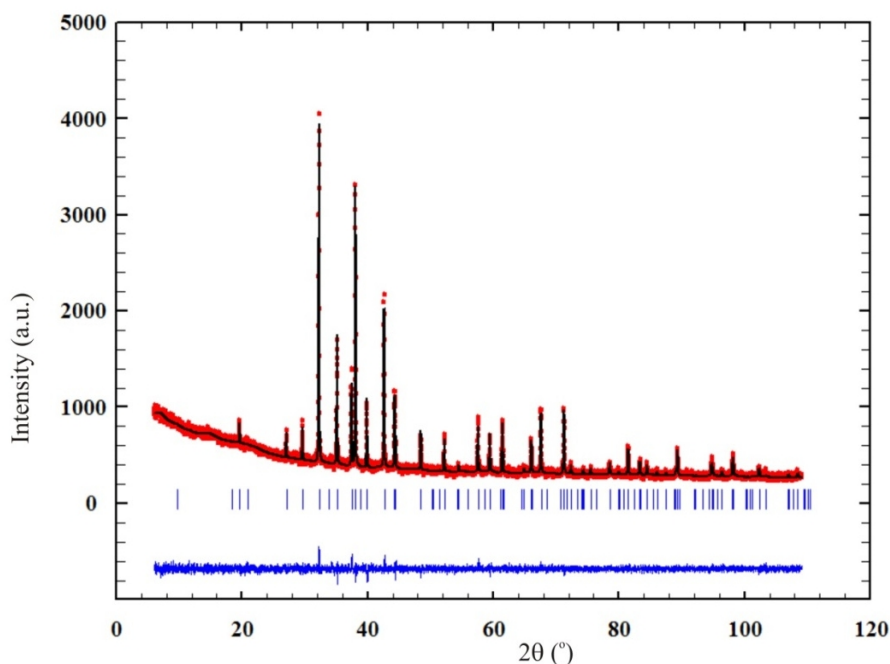


Fig. 5. The observed, calculated and difference X-ray patterns of GdMn_6Sn_6 compound.

homogeneity ranges at investigated temperatures. Crystallographic characteristics of ternary compounds are given in Table 1. The SEM pictures and phase compositions of some alloys are shown in Figs. 3, 4.

The existence of the GdMn_6Sn_6 compound with MgFe_6Ge_6 structure type and its lattice parameters were reported earlier [23]. During present work, the crystal structure of this stannide was refined by X-ray powder

diffraction method. Performed structure refinement confirmed that GdMn_6Sn_6 belongs to MgFe_6Ge_6 structure type (space group $P6/mmm$, $a = 0.55369(2)$ nm, $c = 0.90270(4)$ nm, $R_p = 0.0378$, $R_{\text{wp}} = 0.0484$, $R_{\text{Brag}} = 0.0455$). Refined atomic parameters are listed in Table 2. The observed, calculated and difference X-ray patterns of the GdMn_6Sn_6 compound are shown in Fig. 5.

Comparing the investigated in our work Gd-Mn-Sn

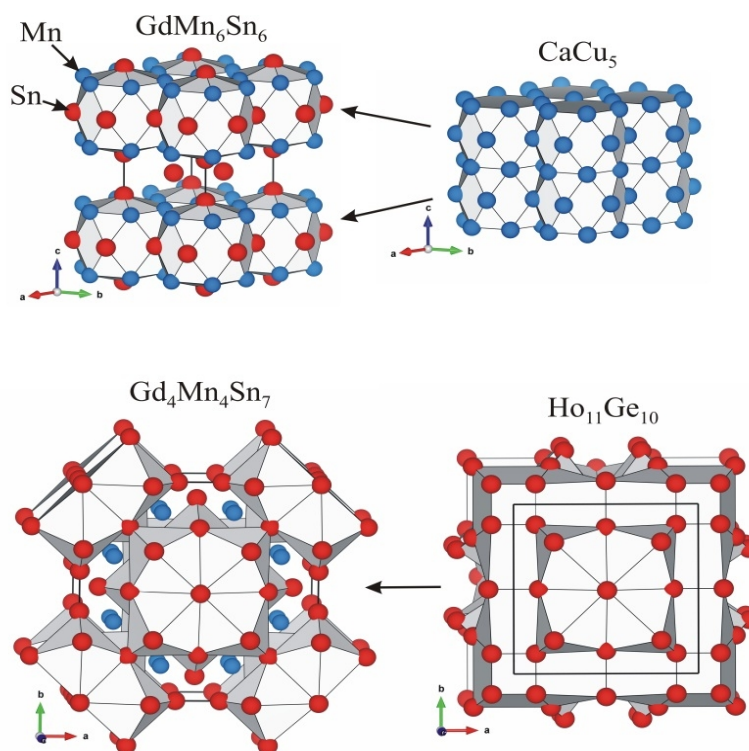


Fig. 6. Stacking of polyhydra in the structures $GdMn_6Sn_6$ and $CaCu_5$ (top), $Gd_4Mn_4Sn_7$ and $Ho_{11}Ge_{10}$ (bottom).

system with studied earlier {Y, Ce, Dy}-Mn-Sn and known in the literature ternary compounds [12] we may note that the R-Mn-Sn ternary systems contain a relatively small number of ternary phases. Series of stannides with $CeNiSi_2$ and $Gd_3Cu_4Ge_4$ structure types are formed only in the systems with rare earths of Cerium group. R-Mn-Sn systems here R is a rare earth element of Yttrium group are characterized by formation of the ternary compounds with $Zr_4Co_4Ge_7$ -type and $MgFe_6Ge_6$ structure types, which are realized in studied Gd-Mn-Sn system.

The structural analysis of ternary compounds formed in the Gd-Mn-Sn system with regard on the coordination polyhydra for smallest and bigger atoms showed that they are related to corresponding structures of the binary compounds (Fig. 6). The structure of $Gd_4Mn_4Sn_7$ is a derivative from the $Ho_{11}Ge_{10}$ structure type in which crystallizes $Gd_{11}Sn_{10}$ binary compound. Main structural fragment is octahedron with additional atoms formed by Sn atoms around Gd atoms. Structure of $GdMn_6Sn_6$ compound is derivative from the structure of $GdMn_{12}$ binary [24] which contains fragments of hexagonal $CaCu_5$ -type. Main structural fragment is hexagonal prism with six additional atoms formed by Sn atoms around Gd

atoms and its deformed derivatives.

Conclusions

Performed in our work investigation of component interaction in the Gd-Mn-Sn system at 673 and 873 K indicated the stability of $GdMn_6Sn_6$ and $Gd_4Mn_4Sn_7$ formed ternary compounds at both temperature of investigation. An influence of the temperature of annealing takes place in character of the phase equilibria in the part of Gd-Mn-Sn system closed to Mn-Sn binary system, above 50 at. % Sn. It is caused by increasing of the liquidus range with increasing of temperature up to 873 K and subsequently absence of $MnSn_2$ binary. Increasing of annealing temperature from 673 to 873 K results in increasing of solubility of Sn in the $GdMn_2$ binary (from 3 to 5 at. %).

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Взаємодія компонентів у потрійній системі Gd-Mn-Sn при 873 і 673 К

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Методами рентгенофазового і мікροструктурного аналізу досліджено взаємодію компонентів у потрійній системі Gd-Mn-Sn у повному концентраційному інтервалі та побудовані діаграми фазових рівноваг за температур 873 К і 673 К. За обох температур дослідження в системі утворюються дві тернарні сполуки GdMn₆Sn₆ (структурний тип MgFe₆Ge₆, просторова група *P6/mmm*) і Gd₄Mn₄Sn₇ (структурний тип Zr₄Co₄Ge₇, просторова група *I4/mmm*). На основі бінарного станіду GdSn₂ зі структурою типу ZrSi₂ встановлено існування твердого розчину включення GdMn_xSn₂ до вмісту 10 ат. % Mn за температур 873 К і 673 К. На основі бінарної сполуки GdMn₂ (структурний тип MgCu₂) утворюється твердий розчин заміщення до вмісту 5 ат. % Sn при 873 К і до вмісту 3 ат. % Sn при 673 К.

Ключові слова: інтерметаліди, потрійна система, фазові рівноваги, кристалічна структура, тверді розчини.